

# HD74LV08A

# Quad. 2-input AND Gates

REJ03D0232-0300Z (Previous ADE-205-250A (Z)) Rev.3.00 May 21, 2004

## **Description**

The HD74LV08A has four two-input AND gates in a 14-pin package.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.3 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 6$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV08AFPEL	SOP-14 pin(JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LV08ARPEL	SOP-14 pin(JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74LV08ATELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

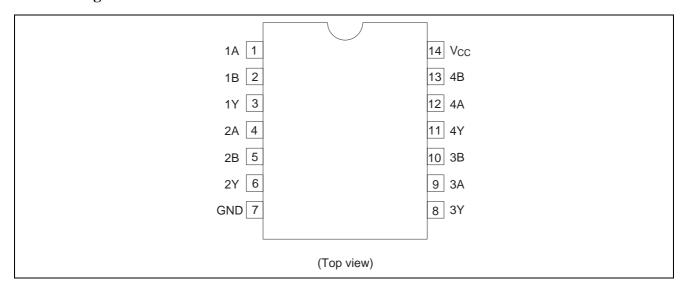
## **Function Table**

## Inputs

A	В	Output Y
Н	Н	Н
L	X	L
X	L	L

Note: H: High level L: Low level X: Immaterial

## **Pin Arrangement**



# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input voltage range*1	VI	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V <sub>CC</sub> + 0.5	V	Output: H or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	I <sub>OK</sub>	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I <sub>O</sub>	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at	P <sub>T</sub>	785	mW	SOP
Ta = $25^{\circ}$ C (in still air)* <sup>3</sup>		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## HD74LV08A

# **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V <sub>CC</sub>	V	
Output current	I <sub>OH</sub>	_	-50	μΑ	V <sub>CC</sub> = 2.0 V
		_	-2	mA	V <sub>CC</sub> = 2.3 to 2.7 V
		_	-6		V <sub>CC</sub> = 3.0 to 3.6 V
		_	-12		V <sub>CC</sub> = 4.5 to 5.5 V
	I <sub>OL</sub>	_	50	μΑ	V <sub>CC</sub> = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	V <sub>CC</sub> = 2.3 to 2.7 V
		0	100		V <sub>CC</sub> = 3.0 to 3.6 V
		0	20		V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

# Logic Diagram



## **DC** Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}C$ 

Item	Symbol	V <sub>CC</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	$V_{IH}$	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_		
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_		
	V <sub>IL</sub>	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$		
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$		
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>CC</sub> - 0.1	_	_	V	$I_{OH} = -50  \mu A$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -12 \text{ mA}$
	V <sub>OL</sub>	Min to Max	_	_	0.1		$I_{OL} = 50 \mu\text{A}$
		2.3	_	_	0.4		I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44		I <sub>OL</sub> = 6 mA
		4.5	_	_	0.55		I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>CC</sub>	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I <sub>OFF</sub>	0	_		5	μΑ	$V_1$ or $V_0 = 0$ V to 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	3.3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

# **Switching Characteristics**

 $V_{CC}=2.5\pm0.2\ V$ 

		Ta =	25°C		Ta = -	40 to 85°C		Test	Test FROM TO	
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	7.9	13.8	1.0	16.0	ns	$C_L = 15  pF$	A or B	Υ
delay time	$t_{PHL}$	_	10.5	17.3	1.0	20.0		$C_L = 50 \text{ pF}$		

 $V_{CC}=3.3\pm0.3\ V$ 

		Ta =	25°C		Ta = -40 to 85°C		Unit	Test	FROM	то	
Item	Symbol	Min	Тур	Max	Min	Max	<del>_</del>	Conditions	(Input)	(Output)	
Propagation	t <sub>PLH</sub>	_	5.6	8.8	1.0	10.5	ns	C <sub>L</sub> = 15 pF	A or B	Υ	
delay time	$t_PHL$	_	7.5	12.3	1.0	14.0		$C_{L} = 50 \text{ pF}$			

 $V_{CC} = 5.0 \pm 0.5~V$ 

		Ta = 1	25°C		Ta = -	40 to 85°C	Test		FROM	ТО
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	4.1	5.9	1.0	7.0	ns	$C_L = 15 pF$	A or B	Υ
delay time	t <sub>PHL</sub>	_	5.5	7.9	1.0	9.0		$C_L = 50 pF$		

## **Operating Characteristics**

 $C_L = 50 pF$ 

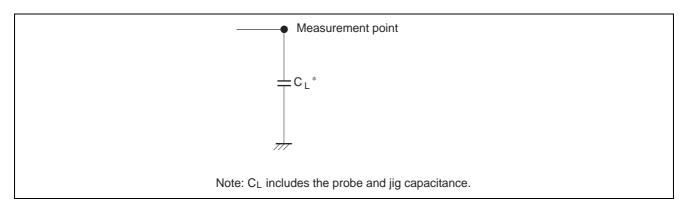
			Ta = 25	°C			
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{PD}$	3.3	_	8.0	_	pF	f = 10 MHz
		5.0	_	10.0	_		

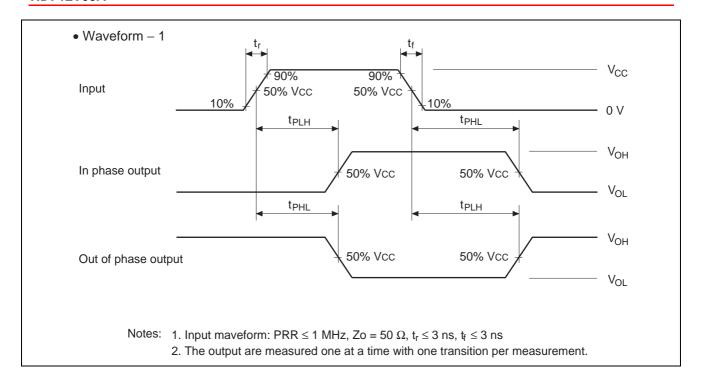
## **Noise Characteristics**

 $C_L = 50 \text{ pF}$ 

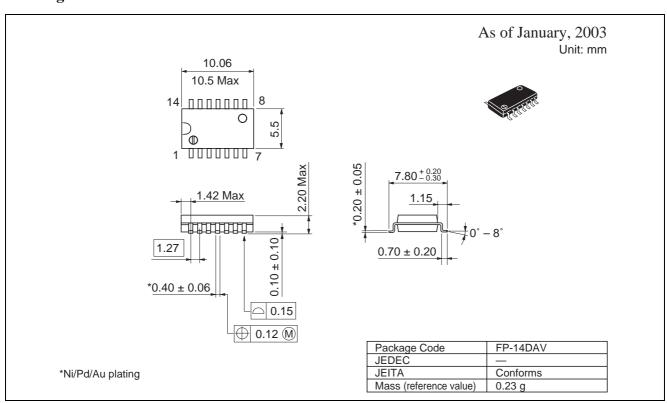
			Ta = 25	5°C			
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Quiet output, maximum dynamic V <sub>OL</sub>	V <sub>OL (P)</sub>	3.3	_	0.2	0.8	V	
Quiet output, minimum dynamic V <sub>OL</sub>	$V_{OL\ (V)}$	3.3	_	-0.1	-0.8	V	
Quiet output, minimum dynamic V <sub>OH</sub>	$V_{\text{OH (V)}}$	3.3	_	3.1	_	V	
High-level dynamic input voltage	V <sub>IH</sub> (D)	3.3	2.31	_	_	V	
Low-level dynamic inout voltage	V <sub>IL (D)</sub>	3.3	_	_	0.99	V	

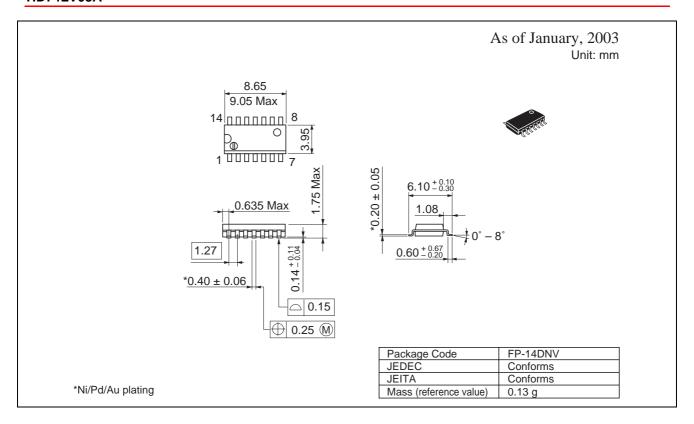
# **Test Circuit**

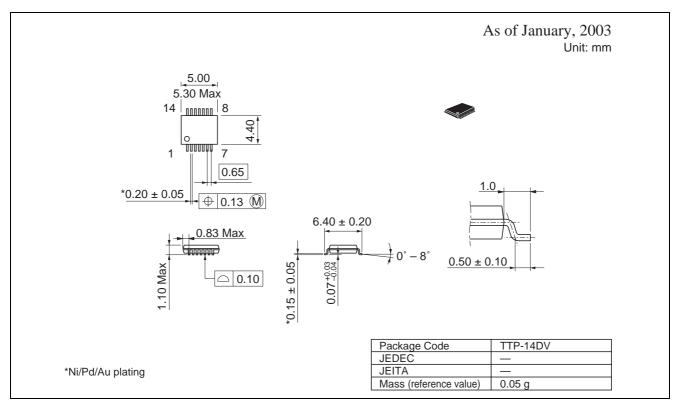




## **Package Dimensions**







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